



Enhanced piezoelectric performance in lead-free piezoceramics of $(1-x)\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3-x\text{Ba}(\text{Sc}_{0.5}\text{Nb}_{0.5})\text{O}_3$

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ABSTRACT

A novel lead-free piezoelectric system, $(1-x)\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3-x\text{Ba}(\text{Sc}_{0.5}\text{Nb}_{0.5})\text{O}_3$ ((1-x)BNT-xBSN), was developed using a conventional solid-state synthesis method. The effect of $\text{Ba}(\text{Sc}_{0.5}\text{Nb}_{0.5})\text{O}_3$ substitution on the crystal structure, microstructure, and electrical properties of $\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3$ were studied systematically. All studied compositions display a pure perovskite phase. Note that the introduction of $\text{Ba}(\text{Sc}_{0.5}\text{Nb}_{0.5})\text{O}_3$ significantly reduces the coercive field of $\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3$. The 0.96BNT-0.04BSN compound exhibits superior piezoelectric properties, with an enhanced piezoelectric coefficient d_{33} of 110 pC/N, nearly double that of the original $\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3$. The $P(E)$ loops and $S(E)$ curves of 0.96BNT-0.04BSN demonstrate a ferroelectric to antiferroelectric phase transition at temperatures exceeding 100 °C. In addition, the 0.96BNT-0.04BSN ceramic also shows a moderate high phase transition temperature of 266 °C. The present study provides a new high piezoelectric performance lead-free ceramic based on $\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3$, which could trigger the interesting in the studies on BNT-Ba(Me)O₃ based Pb-free piezoelectric materials for high piezoelectric performance lead-free materials.

1. Introduction

Piezoelectric ceramics are capable of direct and reversible conversion of electrical energy into mechanical energy, which is widely used in sensors, high-frequency filters, and ultrasonic transducers [1–3]. Lead-based piezoelectric ceramics, particularly $\text{PbTi}_{1-x}\text{Zr}_x\text{O}_3$ (PZT), dominate the commercial market due to their superior piezoelectric properties at the morphotropic phase boundary (MPB) [4]. However, lead is toxic to environment and human health. Therefore, to ensure sustainable development for both humanity and the environment, it is imperative to investigate lead-free piezoelectric ceramics as alternatives to the existing PZT [5–7].

Over recent decades, various potential lead-free piezoelectric ceramics have been developed, including $\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3$ (BNT), $\text{Bi}_{0.5}\text{K}_{0.5}\text{TiO}_3$ (BKT), $\text{K}_{0.5}\text{Na}_{0.5}\text{NbO}_3$ (NN), BaTiO_3 (BT), and their derivatives

[8–16]. BNT is regarded as a promising candidate due to its significant remanent polarization ($P_r = 38 \mu\text{C}/\text{cm}^2$) [17,18]. BNT is a room-temperature perovskite ferroelectric with rhombohedral symmetry (space group $R3c$). It undergoes a ferroelectric-to-paraelectric phase transition around at 320 °C, and a noticeable ferroelectric-to-antiferroelectric transition occurs at ~ 200 °C [19]. However, pure BNT exhibits a significant coercive field ($E_C = 7.3 \text{ kV}/\text{mm}$) and elevated conductivity, complicating the poling process [20]. Consequently, pure BNT ceramic typically demonstrates weak piezoelectric properties, characterized by a low piezoelectric coefficient of $d_{33} = 58 \text{ pC}/\text{N}$ [8]. Various efforts have been undertaken to enhance the piezoelectric properties of BNT by creating BNT-based solid solutions, including $\text{BNT-Bi}(\text{Zn}_{1/2}\text{Ti}_{1/2})\text{O}_3$, $\text{BNT-Bi}(\text{Mg}_{1/2}\text{Ti}_{1/2})\text{O}_3$, and $\text{BNT-Bi}_{0.5}\text{K}_{0.5}\text{TiO}_3$ [21–23].

Following the report of exceptional piezoelectric properties in (1-x)

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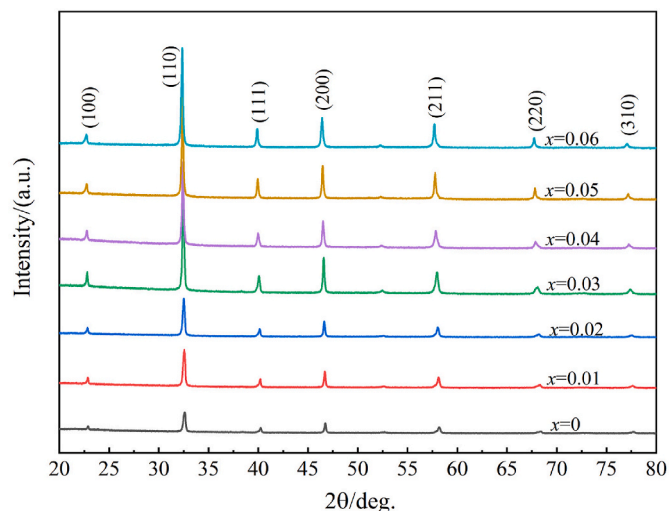


Fig. 1. X-ray diffraction patterns of the $(1-x)\text{BNT}-x\text{BSN}$ ($x = 0.0-0.06$) compounds.

$\text{BNT}-x\text{BaTiO}_3$ near the MPB ($x = 0.06$), several high-performance lead-free ceramics were discovered within the $\text{BNT}-\text{BaMeO}_3$ system, where Me represents a single or mixed cation(s) with an average valence of +4 [19,24–26]. Indeed, large d_{33} values were observed in $(1-x)\text{BNT}-x\text{Ba}(\text{Al}_{0.5}\text{Nb}_{0.5})\text{O}_3$ and our recently reported $(1-x)\text{BNT}-x\text{Ba}(\text{Ni}_{1/3}\text{Nb}_{2/3})\text{O}_3$ systems [27,28]. It is therefore proposed that the introduction of Nb^{5+} could improve the piezoelectric properties of BNT [29]. Nb^{5+} has been shown to enhance domain switching and improve the piezoelectric properties of traditional PZT ceramics by ‘softening’ them [30]. On the other hand, both large d_{33} and high T_C values were observed in the MPB of $x\text{BiScO}_3-(1-x)\text{PbTiO}_3$ ($x = 0.36$) [31]. It is considered that Sc^{3+} can also benefit the piezoelectric properties. We therefore developed a novel binary lead-free piezoelectric system of $(1-x)\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3-x\text{Ba}(\text{Sc}_{0.5}\text{Nb}_{0.5})\text{O}_3$. The crystal structure, microstructure, and piezoelectric, ferroelectric, and dielectric properties were systematically studied.

2. Experimental procedure

Perovskite piezoelectric ceramics of $(1-x)\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3-x\text{Ba}(\text{Sc}_{0.5}\text{Nb}_{0.5})\text{O}_3$ (abbreviated as $(1-x)\text{BNT}-x\text{BSN}$) with x ranging from 0.0 to 0.06 were synthesized using the conventional solid-state method. Bi_2O_3 (99.99 %), Na_2CO_3 (99.8 %), TiO_2 (99.9 %), BaCO_3 (99.95 %), Sc_2O_3 (99.99 %), and Nb_2O_5 (99.9 %) were measured according to the stoichiometric formula. The starting materials were thoroughly mixed using hand milling in an agate mortar, ensuring the powders were as homogeneous as possible. The mixed powders were calcined at 850°C for 3 h, followed by re-milling and pressing into pellets with an 8 mm diameter and 1 mm thickness. The pellets underwent sintering in a covered alumina crucible at 1150°C for 2 h, with a heating and cooling rate of 5°C per minute. To minimize the loss of Bi and Na owing to the volatility during the sintering process, the samples were embedded by the calcined powders.

The crystal structure of the investigated samples was identified by X-ray powder diffractometer (XRD, X’Pert PRO, Huber, Germany) using a $\text{CuK}\alpha$ radiation at 40 kV and 40 mA ($\lambda = 1.5406 \text{ \AA}$). Surface morphology of the ceramics was examined using a HITACHI SU8200 scanning electron microscope (SEM). All ceramics were polished to approximately 0.6 mm thickness for electrical measurements. Then, the polished pellets were uniformly sputtered with gold electrodes on both sides using the magnetron ion sputtering instrument. An aixACCT TF Analyzer 1000 ferroelectricity analyzer (Aachen, Germany) equipped with a Sios Mi-60 laser was employed to measure electric field-induced polarization $P(E)$ and longitudinal strain $S(E)$ curves in a silicone oil bath using a 1 Hz triangular waveform at room temperature. Piezoelectric measurements involved poling all samples in a silicone oil bath at room temperature with a DC electric field of 8 kV/mm for 5 min. The piezoelectric coefficient (d_{33}) of each poled sample was measured with a d_{33} m (ZJ-3, Chinese Academy of Acoustics, Beijing, China) after 24 h of aging. Thermal depoling measurements of the piezoelectric properties were conducted by attaching Ag electrodes at different temperatures for 30 min. The dielectric constant (ϵ_r) and dielectric loss ($\tan\delta$) were analyzed across varying frequencies and temperatures using an HP4294A impedance analyzer (Hewlett-Packard, Palo Alto, CA).

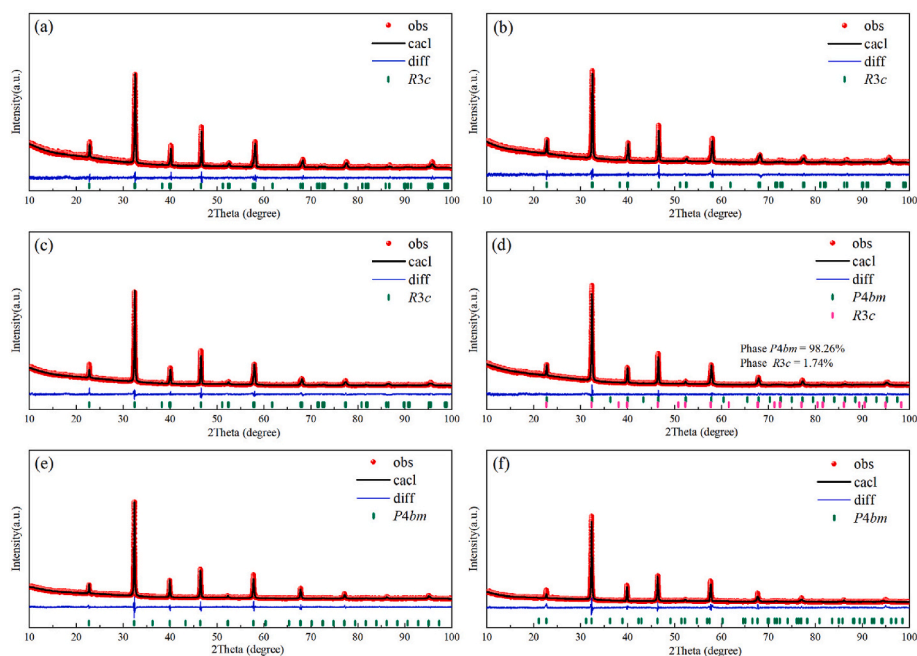


Fig. 2. Rietveld refinement results of $(1-x)\text{BNT}-x\text{BSN}$ ceramics (a) $x = 0.01$, (b) $x = 0.02$, (c) $x = 0.03$, (d) $x = 0.04$, (e) $x = 0.05$, and (f) $x = 0.06$.

Table 1
Details of Rietveld refinement results of XRD patterns of the (1-x)BNT-xBSN ceramics.

Sample	Space group	Atom	x	y	z	U	Cell (Å)	R (%)
x = 0.01	R3c	Bi	0	0	0.2734	0.0001	a = 5.479 c = 13.520	$R_{wp} = 3.28$ $R_p = 2.49$
		Na	0	0	0.2487	0.0534		
		Ba	0	0	0.2734	0.0001		
		Ti/Sc/Nb	0	0	0.0094	0.0033		
		O	0.1130	0.3138	0.0732	0.0551		
x = 0.02	R3c	Bi	0	0	0.2349	0.0086	a = 5.489 c = 13.532	$R_{wp} = 3.61$ $R_p = 2.65$
		Na	0	0	0.2349	0.0086		
		Ba	0	0	0.2349	0.0086		
		Ti/Sc/Nb	0	0	-0.0092	0.0018		
		O	0.1130	0.3138	0.0773	0.0212		
x = 0.03	R3c	Bi	0	0	0.2714	0.0100	a = 5.500 c = 13.574	$R_{wp} = 3.23$ $R_p = 2.30$
		Na	0	0	0.2487	0.0530		
		Ba	0	0	0.2714	0.0100		
		Ti/Sc/Nb	0	0	0.0094	0.0030		
		O	0.1130	0.3138	0.0732	0.0550		
x = 0.04	R3c	Bi	0	0	0.2345	0.0075	a = 5.530 c = 13.539	$R_{wp} = 2.58$ $R_p = 2.00$
		Na	0	0	0.2345	0.0075		
		Ba	0	0	0.2345	0.0075		
		Ti/Sc/Nb	0	0	-0.0120	0.0052		
		O	0.1130	0.3138	0.0752	0.0101		
	P4bm	Bi	0	0.5	0.5358	0.0531	a = 5.517 c = 3.902	
		Na	0	0.5	0.4795	0.0531		
		Ba	0	0	0.4795	0.0531		
		Ti/Sc/Nb	0	0	0.0062	0.0030		
		O1	0	0	0.5203	0.0448		
x = 0.05	P4bm	O2	0.2624	0.2376	0.0175	0.0289	a = 5.524 c = 3.905	$R_{wp} = 3.68$ $R_p = 2.56$
		Bi	0	0.5	0.5153	0.0575		
		Na	0	0.5	0.5153	0.0575		
		Ba	0	0	0.5153	0.0575		
		Ti/Sc/Nb	0	0	-0.0138	0.0004		
	P4bm	O1	0	0	0.4859	0.0699	a = 5.531 c = 4.208	$R_{wp} = 4.23$ $R_p = 2.80$
		O2	0.2700	0.2300	0.0477	0.0304		
		Bi	0	0.5	0.5267	0.0377		
		Na	0	0.5	0.5267	0.0377		
		Ba	0	0	0.5267	0.0377		
x = 0.06	P4bm	Ti/Sc/Nb	0	0	-0.0428	0.0251	a = 5.531 c = 4.208	$R_{wp} = 4.23$ $R_p = 2.80$
		O1	0	0	0.3525	0.0344		
		O2	0.2627	0.2373	-0.0268	0.0581		

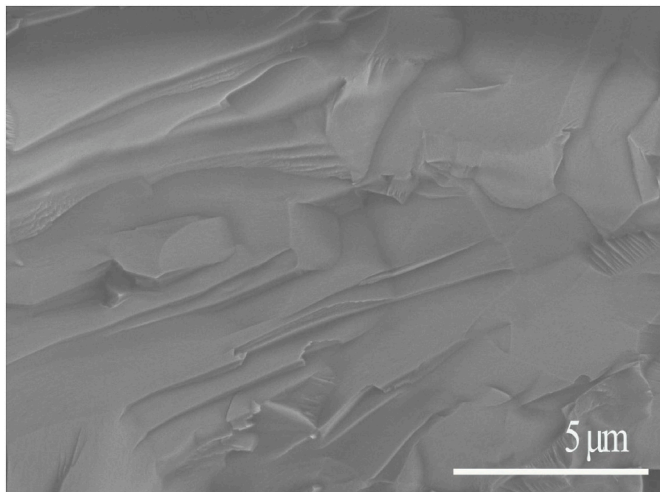


Fig. 3. SEM image of the 0.96BNT-0.04BSN ceramics.

3. Results and discussion

The XRD patterns were used to study the effect of BSN substitution on the phase structure of BNT. As shown in Fig. 1, pure perovskite structure can be observed for all investigated samples, without any noticeable

impurities. Note that the (200) peak around at $2\theta = 40$ gradually shifts to a lower 2θ angle with increasing BSN content (x), indicating the lattice expansion. This may be attributed to the larger ionic radius of Ba^{2+} (1.35 Å) compared to Bi^{3+} (1.03 Å) and Na^+ (0.98 Å) at the A-site [32]. It therefore can be concluded that the BSN can be well incorporated into BNT matrix and lead to the lattice expansion.

The impact of BSN on BNT's phase structure was analyzed by refining XRD data for all samples using GSAS software [33], with results presented in Fig. 2. The details of the refined parameters are listed in Table 1. As can be seen, samples for $x \leq 0.03$ can be well refined by using the same rhombohedral symmetry to the pristine BNT (Fig. 2(a–c)). Notably, with BSN content increasing to $x = 0.04$, a mixed *P4bm* and *R3c* phases coexist (Fig. 2(d)), indicating the so-called MPB could be located around at $x = 0.04$. For further increasing the BSN content, such as $x = 0.05$ and $x = 0.06$ (Fig. 2(e and f)), the samples were transformed into the single *P4bm* phase. The findings indicate that incorporating BSN into BNT triggers a phase transition from rhombohedral *R3c* to tetragonal *P4bm*, with both *R3c* and *P4bm* phases coexisting at $x = 0.04$.

Fig. 3 shows the SEM micrograph of selected BSN doped BNT ceramics with $x = 0.04$. As can be seen, the ceramic shows a dense and homogeneous microstructure. This suggests that the BNT-BSN ceramics were densely sintered.

Fig. 4 illustrates the room temperature evolution of polarization $P(E)$ loops and bipolar strain $S(E)$ curves as a function of the electric field for (1-x)BNT-xBSN ceramics with x values of 0.02, 0.04, and 0.05, near the MPB composition. Fig. 4(a) shows that all samples exhibit well saturated $P(E)$ hysteresis loops, indicating typical ferroelectrics. Notably, $P(E)$

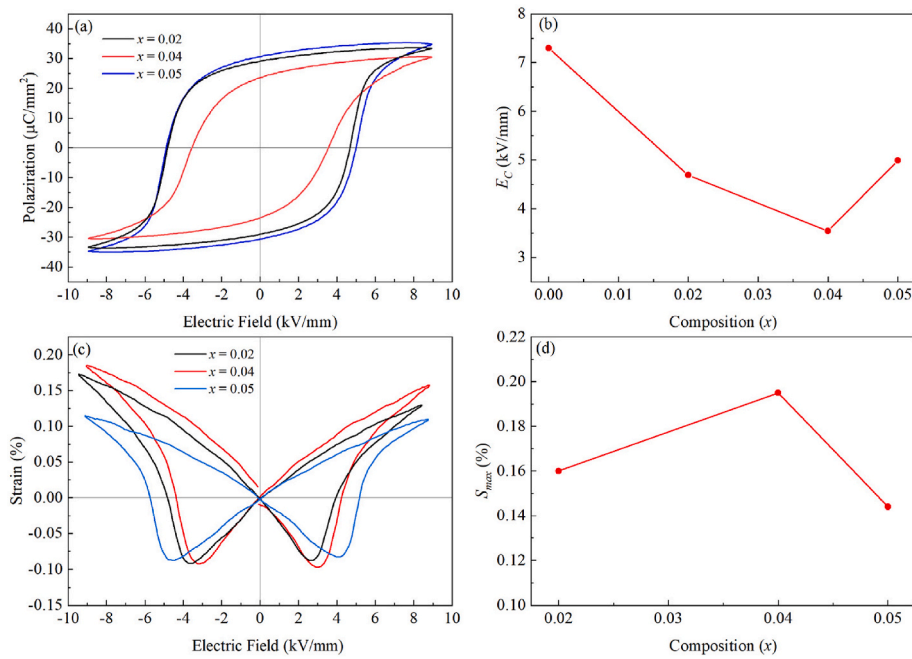


Fig. 4. (a) $P(E)$ hysteresis loops, (b) E_C , (c) bipolar $S(E)$ curves, and (d) S_{max} of the (1-x)BNT-xBSN ceramics ($x = 0.02, 0.04, \text{ and } 0.05$).

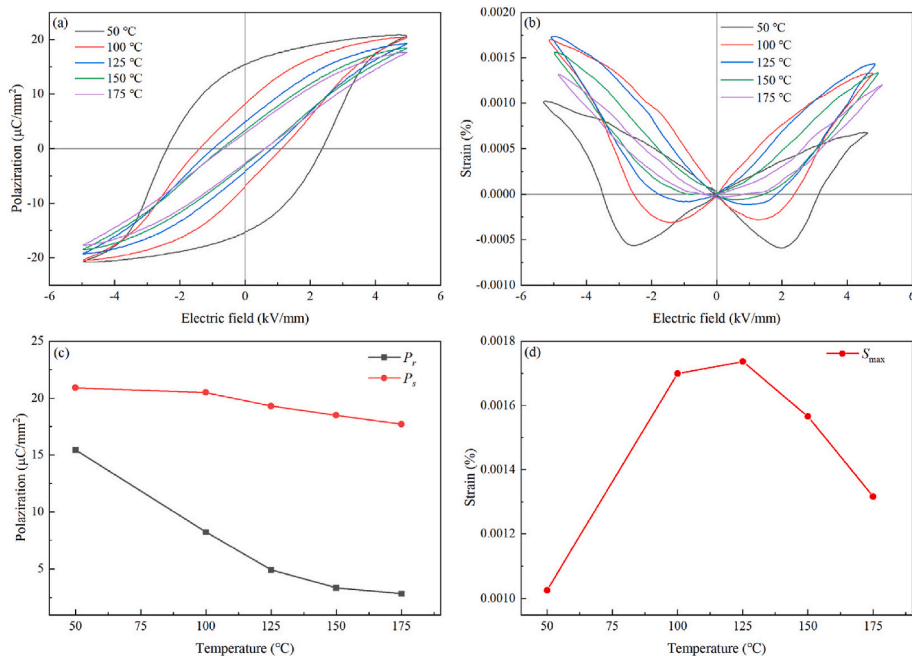


Fig. 5. (a) $P(E)$ ferroelectric loops, (b) bipolar $S(E)$ curves, (c) P_s and P_r , and (d) the maximum strain for the 0.96BNT-0.04BSN ceramics as a function of temperature.

loops in the (1-x)BNT-xBSN system remain unconstricted even at a high BSN substitution level of $x = 0.05$, indicating the sample retains its ferroelectric order (FE). This phenomenon is much different from the previously reported BNT-based systems, in which constricted $P(E)$ loops were usually observed for substitution contents beyond the MPB compositions. As can be seen, the introduction of BSN significantly reduces the coercive field (E_C) of BNT [20]. The E_C values are 4.69, 3.54, and 4.99 kV/mm for the compositions of $x = 0.02, 0.04, \text{ and } 0.05$, respectively (Fig. 4(b)). The values are significantly lower compared to pristine BNT, which has an E_C of 7.3 kV/mm. The reduced E_C can promote the domain switching during the poling process, and thus benefit the piezoelectric performance.

The bipolar $S(E)$ curves of all the investigated samples show an archetypal butterfly shape (Fig. 4(c)), which indicate the FE nature of the piezoelectric ceramics as well. Fig. 4(d) illustrates the total strain of the bipolar wave, defined as the absolute difference between its maximum and minimum strain values. The total strain increases non-monotonically with x , peaking at 0.195 % for the MPB composition of $x = 0.04$ [34].

The thermal stability of polarization and strain-field behavior was evaluated by conducting temperature-dependent ferroelectric measurements on the 0.96BNT-0.04BSN sample. At 50 °C, the $P(E)$ loop is nearly saturated, demonstrating a characteristic ferroelectric behavior (Fig. 5(a)). However, when temperature reaches and exceeds 100 °C, the

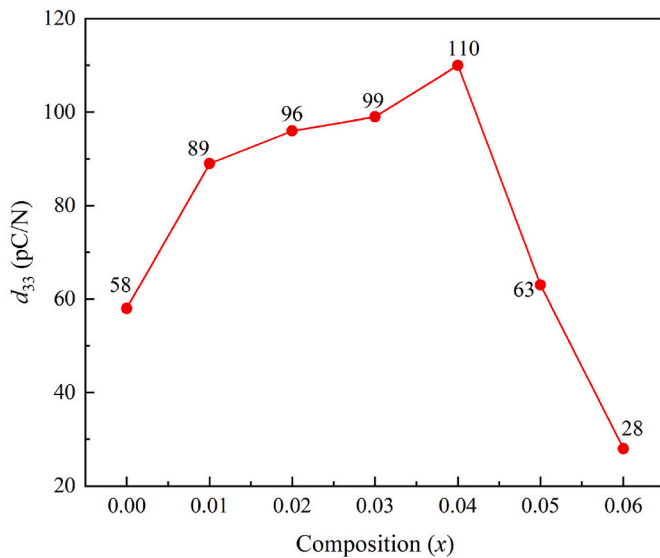


Fig. 6. The small-signal piezoelectric coefficient (d_{33}) as a function of BSN composition of (1-x)BNT-xBSN ceramics.

$P(E)$ loops become constricted. Both E_C and P_r drop sharply, suggesting an incipient presence of the anti-ferroelectric (AFE) order. With a further increase in temperature, the loops continuously become slimmer and more inclined, while P_s , P_r and E_C are further reduced (Fig. 5(c)). Fig. 5 (b) illustrates the bipolar $S(E)$ curves. The $S(E)$ curve displays a characteristic butterfly shape at 50 °C. As the temperature rises, the curve begins to change shape. The sudden increase in maximum strain, coupled with the near disappearance of negative strain around 150 °C, indicates a transition from the FE to AFE phase.

Fig. 5(d) illustrates that S_{max} rises from 50 °C to 125 °C before declining, peaking at 125 °C, indicating a phase transition between 50 °C and 125 °C. The observed phenomenon can be explained by the dominance of the FE phase below 100 °C, resulting in minimal contribution of the FE-to-AFE transition to the strain. The AFE phase of BNT-BSN predominates when the temperature surpasses 100 °C, significantly contributing to the strain through the FE-to-AFE phase transition. This

phenomenon has also been observed in various other BNT-based lead-free ceramics [23,35].

The small-signal piezoelectric coefficient (d_{33}) of all ceramics is shown in Fig. 6. Similar to the change of total strain, the d_{33} is also enhanced non-monotonously with increasing x . The substitution of BSN significantly improves the piezoelectric coefficient. A maximum d_{33} value of 110 pC/N has been observed in the MPB composition of 0.96BNT-0.04BSN, which is almost twice of the pristine BNT. The piezoelectric coefficient of 0.96BNT-0.04BSN ceramics surpasses many other BNT-based lead-free systems, such as 0.9625BNT-0.0375BZT ($d_{33} = 92$ pC/N) and 0.93BNT-0.07BMN ($d_{33} = 94$ pC/N), and is comparable to 0.94BNT-0.06BaTiO₃ ($d_{33} = 155$ pC/N) [19,22,23,36]. The enhanced piezoelectric properties can be ascribed to the reduced E_C , facilitating the complete poling of ceramics during the process. Furthermore, the improved piezoelectric properties might be associated with the reduced depolarization temperature (T_d), which decreases from approximately 200 °C in pristine BNT to around 130 °C in 0.96BNT-0.04BSN, as will be elaborated in the subsequent section. A similar correlation between the piezoelectric coefficient and T_d has been noted in conventional (1-x)BNT-xBaTiO₃ ceramics [37]. The loss of macro-ordering and reversion to a disordered micro-domain texture at T_d indicates the stability of ferroelectric domains [38]. The decreased T_d suggests that the introduction of BSN makes the ferroelectric domains less stable. Consequently, reorienting the 90 °C domains is facilitated. Therefore, enhanced piezoelectric properties were observed in the present (1-x)BNT-xBSN ceramics.

Since (1-x)BNT-xBSN ceramics exhibit favorable piezoelectric coefficients, the T_C is another important factor for practical applications. To analyze the phase transition and determine the actual T_C , the temperature-dependent dielectric constant (ϵ_r) and loss ($\tan\delta$) of (1-x)BNT-xBSN ceramics ($x = 0.02, 0.04, \text{ and } 0.05$) were measured across various frequencies from room temperature to 600 °C (Fig. 7(a-c)). All ceramics displayed two dielectric anomalies, indicating the FE-to-AFE phase transition temperatures, T_d and T_m . Notably, a relaxor characteristic as a function of frequency at low temperature (<200 °C) has been observed for all investigated compounds, which could be ascribed to the structural disorder and compositional fluctuations. This effect has similarly been noted in other lead-free ceramics based on BNT [16,17]. The evolution of T_m and T_d derived from the dielectric spectroscopies are shown in Fig. 7(d). As can be seen, both T_m and T_d show decrease

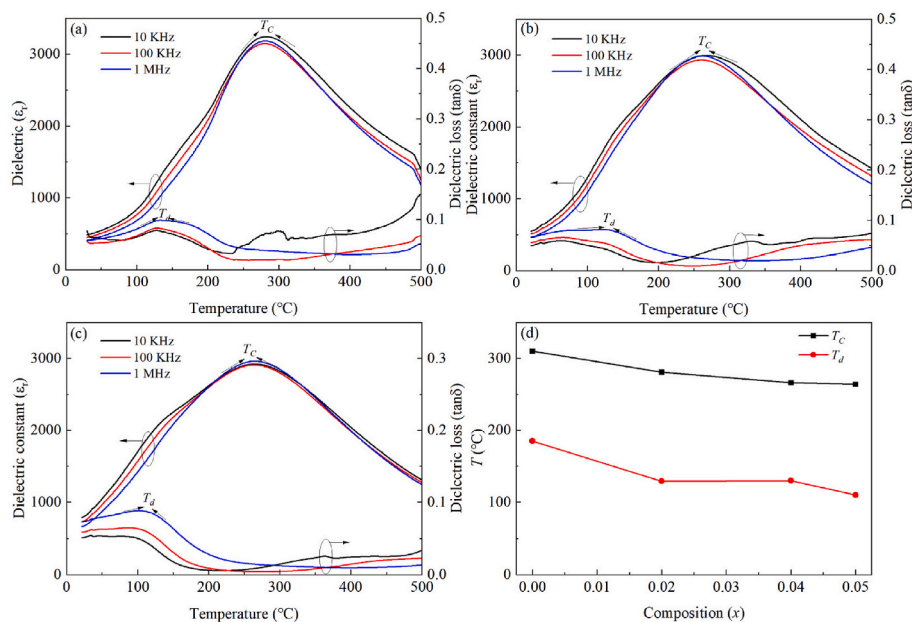


Fig. 7. The temperature dependence of dielectric constant (ϵ_r) and dielectric loss ($\tan\delta$) of the (a) $x = 0.02$, (b) $x = 0.04$, and (c) $x = 0.05$ ceramics, (d) T_C and T_d as function of composition x .

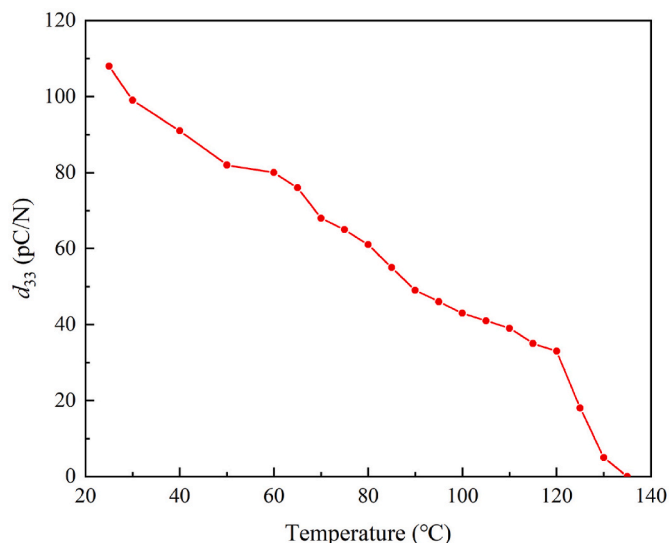


Fig. 8. Temperature dependence of small-signal d_{33} of 0.96BNT-0.04BSN as function of annealing temperatures.

tendency with the increasing BSN content. The T_m and T_d values of the MPB composition 0.96BNT-0.04BSN are 266 and 130 °C, respectively.

Fig. 8 shows the effect of thermal depoling on the piezoelectric properties of 0.96BNT-0.04BSN ceramics with the optimal d_{33} value at room temperature. As can be seen, the small-signal d_{33} value of 0.96BNT-0.04BSN steadily decreases with increasing temperature. However, when the annealing temperature is approaching the T_d , the d_{33} value decreases rapidly, and tends to zero, which corresponds to the FE-to-AFE phase transition. The result agrees well with the above mentioned temperature dependence $P(E)$ and $S(E)$ measurements, as well as the dielectric spectroscopy of the 0.96BNT-0.04BSN ceramics.

4. Conclusions

In summary, a novel lead-free piezoelectric system, $(1-x)\text{Bi}_{0.5}\text{Na}_{0.5}\text{TiO}_3\text{-}x\text{Ba}(\text{Sc}_{0.5}\text{Nb}_{0.5})\text{O}_3$ ($0.00 \leq x \leq 0.06$), was developed and synthesized via the conventional solid solution method. All compositions display a perovskite structure, with the addition of BSN to BNT ceramics causing a phase transition from rhombohedral $R3c$ to tetragonal $P4bm$. The incorporation of BSN effectively reduces the E_C of pure BNT and enhances its piezoelectric properties. Composition for 0.96BNT-0.04BSN shows an enhanced piezoelectric coefficient of $d_{33} = 110$ pC/N, which is much higher than that of the pristine BNT. In addition, the 0.96BNT-0.04BSN compound also exhibit a moderate high T_m of 266 °C. This study reaffirms that high piezoelectric performance is achievable in lead-free BNT-BaMeO₃ systems.

CRediT authorship contribution statement

Weihao Li: Writing – review & editing, Writing – original draft, Software, Formal analysis, Data curation. **Zhao Pan:** Writing – review & editing, Supervision, Project administration, Methodology, Funding acquisition, Conceptualization. **Mengqi Ye:** Writing – review & editing, Formal analysis, Data curation. **Jin Liu:** Writing – review & editing, Data curation. **Maocai Pi:** Writing – review & editing, Data curation. **Jie Zhang:** Writing – review & editing, Data curation. **Xubin Ye:** Writing – review & editing, Data curation. **Xiao Wang:** Data curation. **Nianpeng Lu:** Data curation. **Laijun Liu:** Writing – review & editing, Formal analysis, Data curation. **Enxiu Wu:** Writing – review & editing, Supervision, Funding acquisition. **Youwen Long:** Writing – review & editing, Supervision, Funding acquisition.

Declaration of competing interest

The authors declare no competing financial interests.

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